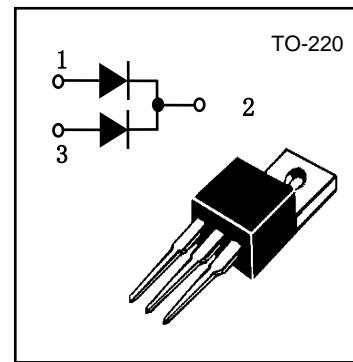


APPLICATIONS

- High efficiency switch mode power supplies
- Free wheeling diodes, polarity protection application

FEATURES

- Common cathode structure
- Low power loss, high efficiency
- High Operating Junction Temperature.
- Guard ring for overvoltage protection, High reliability
- ROHS product

**ABSOLUTE RATINGS(Tc=25 °C)**

Parameter	SYMBOL	Value	UNIT
Repetitive peak reverse voltage	VRRM	45	V
Maximum DC blocking voltage	VDC	45	V
Average forward current	per device	10	A
	per diode		
Surge non repetitive forward current	IFSM	80	A
Maximum junction temperature	TJ	150	°C
Storage temperature range	TSTG	-40~+150	°C

Electronic Characteristics(Tc=25 °C)

Parameter	Tests conditions		Value (min)	Value (typ)	Value (max)	UNIT
IR	TJ=25°C	VR=VRRM			50	uA
	TJ=125°C				50	mA
VF	TJ=25°C	IF=5A		0. 52	0. 58	V
	TJ=125°C				0. 48	V

THERMAL CHARACTERISTICS

Parameter	Symbol	Value (min)	Value (max)	Unit
Thermal resistance from junction to case	Rth(j-c)		1.9	°C/W

ELETICAL CHARACTERISTICS(CURVES)

